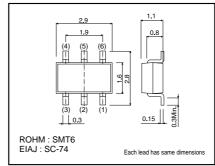
# Power management (dual digital transistors) IMD10A

### Features

- 1) Two digital class transistors in a SMT package.
- 2) Up to 500mA can be driven.
- Low Vce(sat) of drive transistors for low power dissipation.

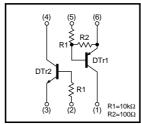
# ●Dimensions (Unit:mm)



# ● Package, marking, and packaging specifications

Part No.	IMD10A
Package	SMT6
Marking	D10
Code	T108
Basic ordering unit (pieces)	3000

# ●Equivalent circuit



# ● Absolute maximum ratings (Ta=25°C)

### DTr<sub>1</sub>

Parameter	Symbol	Limits	Unit
Supply voltage	Vcc	-50	V
Input voltage	Vin	−5 to +5	V
Collector current	Ic	-500	mA

### DTr<sub>2</sub>

Parameter	Symbol	Limits	Unit
Collector-base voltage	Vсво	50	V
Collector-emitter voltage	VCEO	50	V
Emitter-base voltage	Vево	5	V
Collector current	Ic	100	mA

### Total

Parameter	Symbol	Limits	Unit
Power dissipation	Pd	300(TOTAL)	mW *
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

<sup>\* 200</sup>mW per element must not be exceeded.

# ●Electrical characteristics (Ta=25°C)

### DTr<sub>1</sub>

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Lancet contract	V <sub>I(off)</sub>	_	_	-0.3	V	Vcc= -5V , Io= -100μA
Input voltage	V <sub>I</sub> (on)	-1.5	_	_	1 V	Vo= -0.3V , Io= -100mA
Output voltage	V <sub>O(on)</sub>	_	-0.1	-0.3	V	lo= -100mA , l≔ -5mA
Input current	lı .	_	_	-25	mA	V <sub>I</sub> = -2V
Output current	IO(off)	_	_	-0.5	μΑ	Vcc= -50V , Vi=0V
DC current gain	Gı	68	_	_	_	lo= -100mA , Vo= -5V
Transition frequency	f⊤	_	200	_	MHz	Vc== -10V , Ie=50mA , f=100MHz *
Input resistance	R <sub>1</sub>	70	100	130	Ω	_
Resistance ratio	R <sub>2</sub> / R <sub>1</sub>	80	100	120	_	_

<sup>\*</sup> Transition frequency of the device.

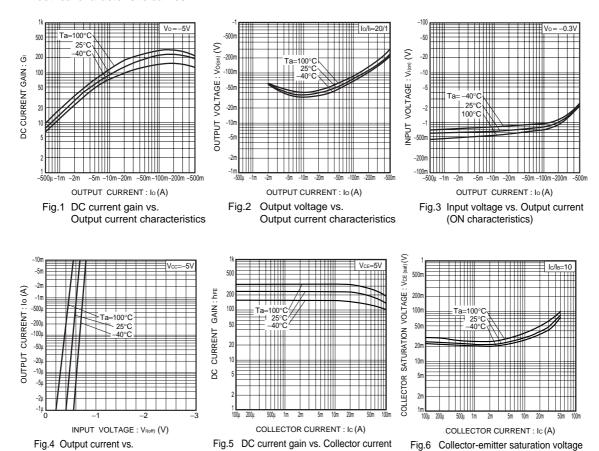
### DTr<sub>2</sub>

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	50	_	_	V	Ic=50μA
Collector-emitter breakdown voltage	BVceo	50	_	_	V	Ic=1mA
Emitter-base breakdown voltage	ВVево	5	_	_	V	Iε=50μA
Collector cutoff current	Ісво	_	_	0.5	μА	Vcb=50V
Emitter cutoff current	ІЕВО	_	_	0.5	μА	V <sub>EB</sub> =4V
Collector-emitter saturation voltage	VCE(sat)	_	_	0.3	V	Ic=10mA , I <sub>B</sub> =1mA
DC current transfer ratio	hfe	100	250	600	_	VcE=5V , Ic=1mA
Transition frequency	f⊤	_	250	_	MHz	Vc=10V , I=-5mA , f=100MHz *
Input resistance	R <sub>1</sub>	7	10	13	kΩ	_

 $<sup>\*</sup>$  Transition frequency of the device.

### •Electrical characteristic curves

Input voltage (OFF characteristics)



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vs. Collector current

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